

P-Channel 200-V (D-S) MOSFET

Key Features:

- Low $r_{DS(on)}$ trench technology
- Low thermal impedance
- Fast switching speed

Typical Applications:

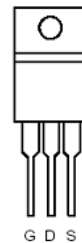
- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (m Ω)	I_D (A)
-200	150 @ $V_{GS} = -10V$	-16.3
	280 @ $V_{GS} = -5.5V$	-12.0

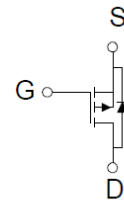


RoHS
COMPLIANT
HALOGEN
FREE

TO-220CFM



Top View



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	-200	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ^a	I_D	-16.3	A
Pulsed Drain Current ^b			
Continuous Source Current (Diode Conduction) ^a	I_S	-59	A
Power Dissipation ^a	P_D	60	W
Operating Junction and Storage Temperature Range			

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	62.5	$^\circ\text{C}/\text{W}$
Maximum Junction-to-Case	$R_{\theta JC}$	1	

Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

Electrical Characteristics

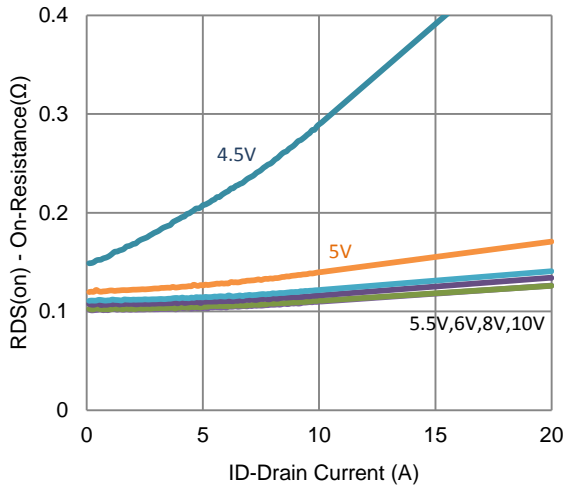
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250 \mu A$	-1			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -160 V, V_{GS} = 0 V$			-1	uA
		$V_{DS} = -160 V, V_{GS} = 0 V, T_J = 55^\circ C$			-25	
On-State Drain Current	$I_{D(on)}$	$V_{DS} = -5 V, V_{GS} = -10 V$	-30			A
Drain-Source On-Resistance	$r_{DS(on)}$	$V_{GS} = -10 V, I_D = -13 A$			150	m Ω
		$V_{GS} = -5.5 V, I_D = -10.4 A$			280	
Forward Transconductance	g_{fs}	$V_{DS} = -15 V, I_D = -13 A$		30		S
Diode Forward Voltage	V_{SD}	$I_S = -28.5 A, V_{GS} = 0 V$		-0.86		V
Dynamic						
Total Gate Charge	Q_g	$V_{DS} = -100 V, V_{GS} = -5.5 V,$ $I_D = -13 A$		134		nC
Gate-Source Charge	Q_{gs}			53		
Gate-Drain Charge	Q_{gd}			55		
Turn-On Delay Time	$t_{d(on)}$	$V_{DS} = -100 V, R_L = 7.7 \Omega,$ $I_D = -13 A,$ $V_{GEN} = -10 V, R_{GEN} = 6 \Omega$		26		ns
Rise Time	t_r			52		
Turn-Off Delay Time	$t_{d(off)}$			286		
Fall Time	t_f			136		
Input Capacitance	C_{iss}	$V_{DS} = -15 V, V_{GS} = 0 V, f = 1 MHz$		10930		pF
Output Capacitance	C_{oss}			496		
Reverse Transfer Capacitance	C_{rss}			348		

Notes

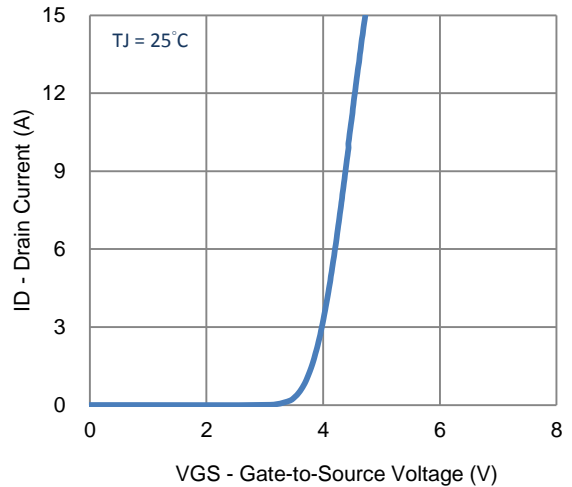
- Pulse test: PW \leq 300us duty cycle \leq 2%.
- Guaranteed by design, not subject to production testing.

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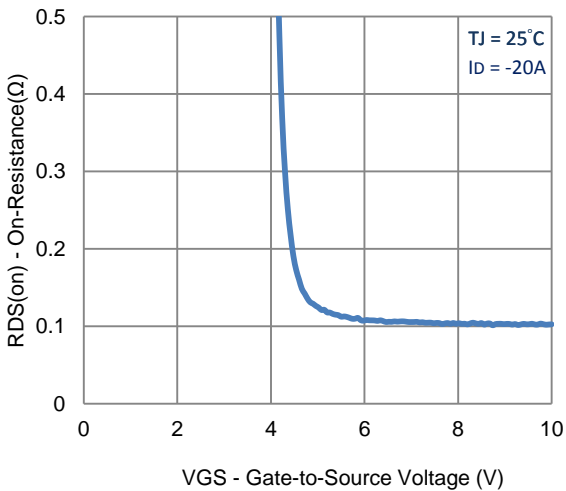
Typical Electrical Characteristics



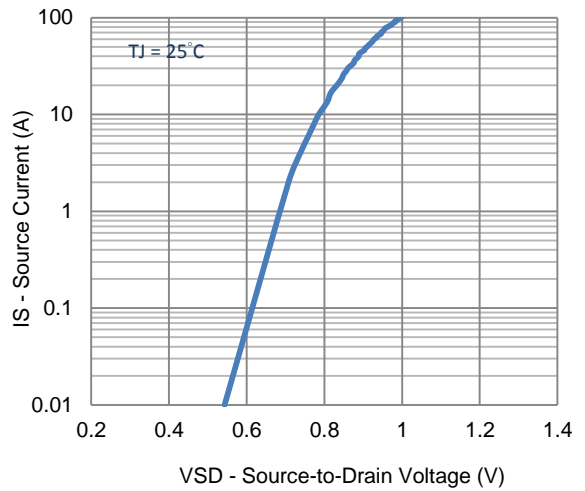
1. On-Resistance vs. Drain Current



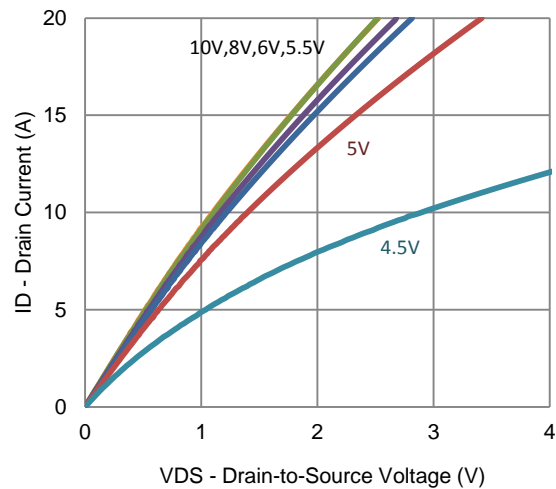
2. Transfer Characteristics



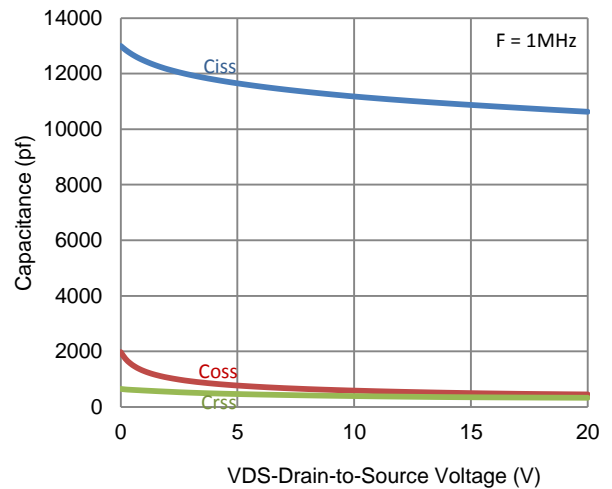
3. On-Resistance vs. Gate-to-Source Voltage



4. Drain-to-Source Forward Voltage

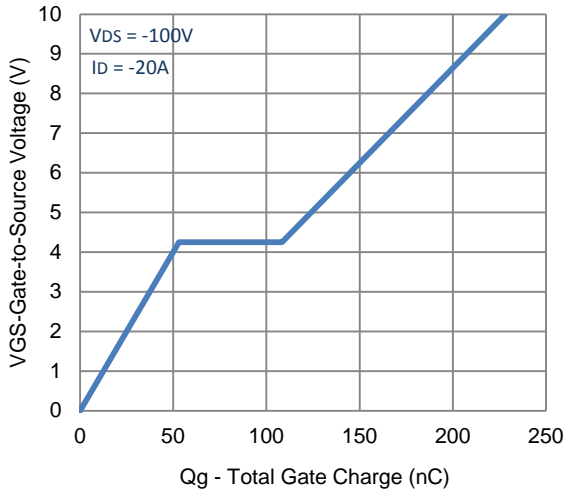


5. Output Characteristics

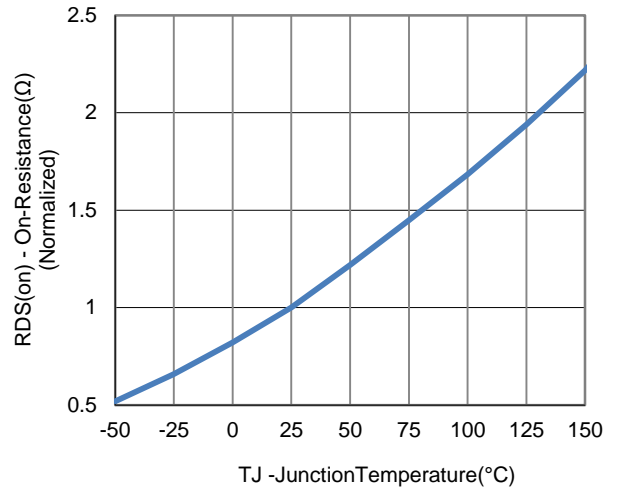


6. Capacitance

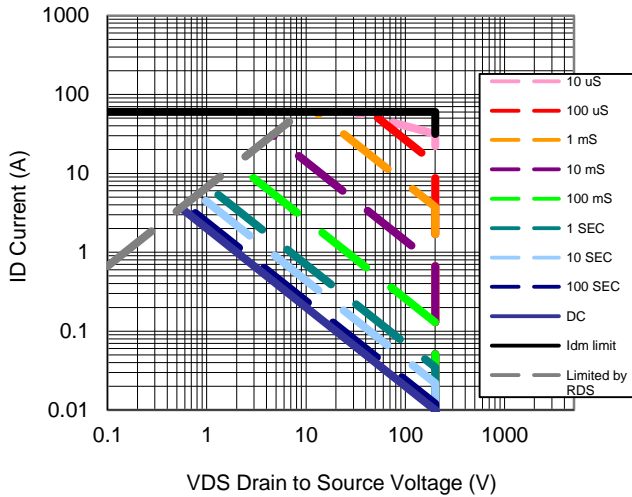
Typical Electrical Characteristics



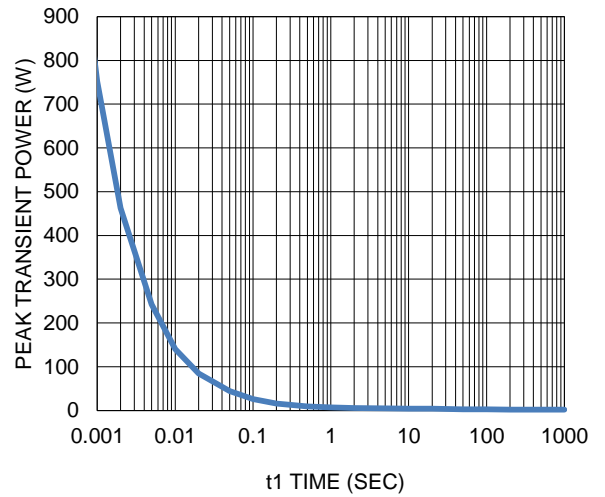
7. Gate Charge



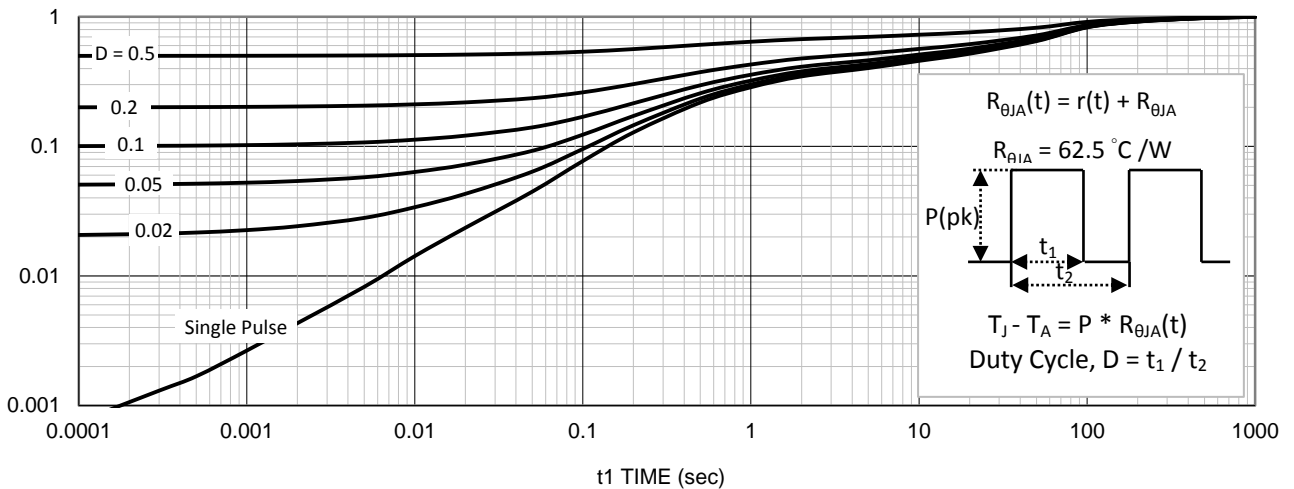
8. Normalized On-Resistance Vs Junction Temperature



9. Safe Operating Area



10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

Package Information

